TOSHIBA Photocoupler Photorelay

TLP222G, TLP222G-2

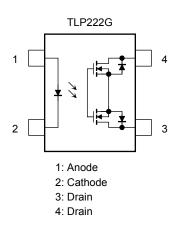
Cordless Telephones PBX Modems

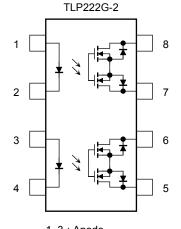
The Toshiba TLP222G series consist of a gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in a DIP package.

The TLP222G series are a bi-directional switch, which can replace mechanical relays in many applications.

- TLP222G: 4-pin DIP (DIP4), 1-channel type (1-form-A)
- TLP222G-2: 8-pin DIP (DIP8), 2-channel type (2-form-A)
- Peak Off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 120 mA (max)
- On-state resistance: 35Ω (max, t < 1 s)
- On-state resistance: 50 Ω (max, continuous)
- Isolation voltage: 2500 Vrms (min)
- BSI approved: BS EN60065:2002, certificate no.8773 BS EN60950-1:2002, certificate no.8774

Pin Configuration (top view)

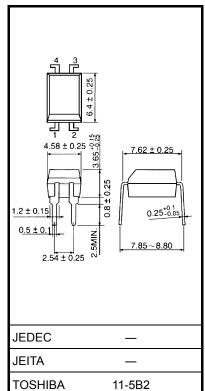




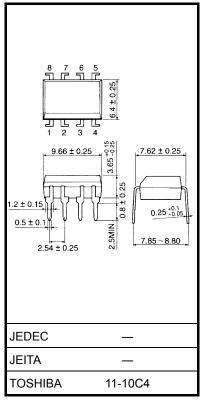
: Anode
: Cathode
: Drain D1
: Drain D2

7 : Drain D3

8 : Drain D4



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)

Unit: mm

Absolute Maximum Rating (Ta = 25°C)

	Cha	racteristics		Symbol	Rating	Unit
LED	Forward curr	rent		١ _F	50	mA
	Forward curr	ent derating (Ta ≧ 25°C)	∆l _F /°C –0.5		mA/°C
	Peak forward (100 μs puls			I _{FP} 1		А
	Reverse volt	age		V _R	5	V
	Junction tem	perature		Тj	125	°C
	Off-state out	put terminal v	oltage	VOFF	350	V
		TLP222G				
	On-state current		One channel operation	I _{ON}	120	mA
Detector		TLP222G-2	Two channel operations (Note 1)	ON	120	
Detector		TLP222G		∆l _{ON} /°C		
	On-state current derating (Ta \geq 25°C)		One channel operation		-1.2	mA/°C
		TLP222G-2	Two channel operations (Note 1)			
	Junction tem	perature		Тj	125	°C
Storage to	emperature ra	ange		T _{stg}	-55 to 125	°C
Operating	Operating temperature range				-40 to 85	°C
Lead sold	lering tempera	ature (10 s)		T _{sol}	260	°C
Isolation	Isolation voltage (AC, 1 min, R.H. \leq 60%) (Note 2)				2500	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Two channels operating simultaneously.
- Note 2: Device considered a two-terminal device: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{DD}	—	—	280	V
Forward current	١ _F	5	7.5	25	mA
On-state current	I _{ON}	_	_	100	mA
Operating temperature	T _{opr}	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrica	Characteristics	(Ta = 25°C)
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	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V _F	$I_F = 10 \text{ mA}$	1.0	1.15	1.3	V
LED	Reverse current	I _R	$V_R = 5 V$	_	_	10	μA
	Capacitance	CT	V = 0, f = 1 MHz	_	30	_	рF
Detector	Off-state current	IOFF	V _{OFF} = 350 V	_	_	1	μA
Detector	Capacitance	COFF	V = 0, f = 1 MHz	_	30	_	pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	I _{ON} = 120 mA	_	1	3	mA
Return LED current	I _{FC}	I _{OFF} = 100 μA	0.1	_	_	mA
On-state resistance	Pou	I_{ON} = 120 mA, I_F = 5 mA, t < 1 s	—	25	35	Ω
	R _{ON}	$I_{ON} = 120$ mA, $I_F = 5$ mA, continuous	_	35	50	52

Isolation Characteristics (Ta = 25°C)

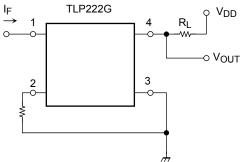
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	$V_{S} = 0 V, f = 1 MHz$	—	0.8	—	pF
Isolation resistance	R _S	$V_S = 500 \text{ V}, \text{ R.H.} \leq 60\%$	5×10^{10}	10 ¹⁴	_	Ω
Isolation voltage	BVS	AC, 1 min	2500	_	_	Vrms
		AC, 1 s, in oil		5000	_	VIIIIS
		DC, 1 min, in oil	—	5000	_	Vdc

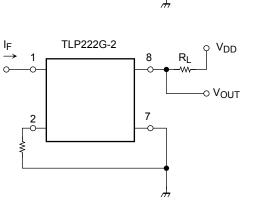
Switching Characteristics (Ta = 25°C)

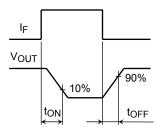
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}	$R_L = 200 \Omega$	_	0.3	1	ms
Turn-off time	tOFF	$V_{DD} = 20 \text{ V}, \text{ I}_{\text{F}} = 5 \text{ mA}$ (Note 3)		0.1	1	1115

Note 3: Switching time test circuit

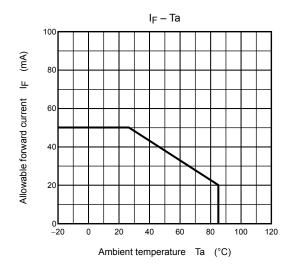
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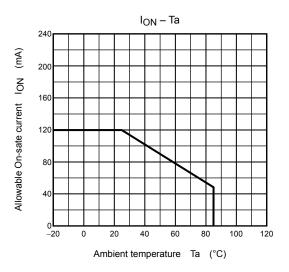


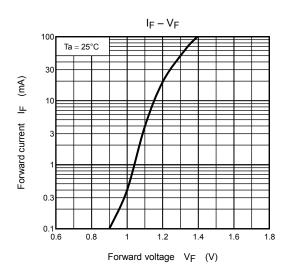


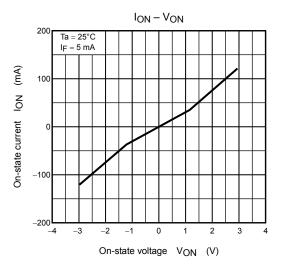


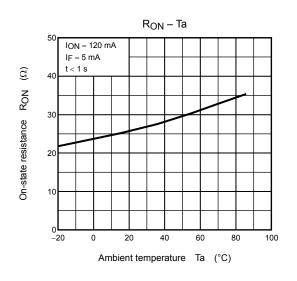
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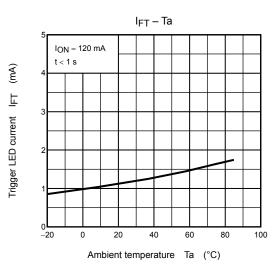




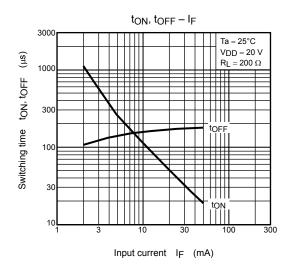


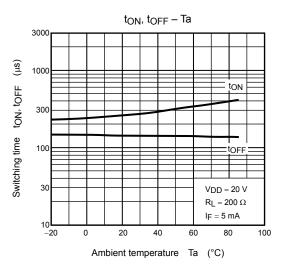


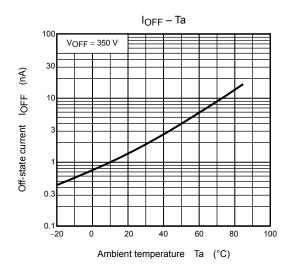




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